MRS1504T3G, NRVS1504T3G

Surface Mount Standard Recovery Power Rectifier

SMB Power Surface Mount Package

Features mesa epitaxial construction with glass passivation. Ideally suited for high frequency switching power supplies; free wheeling diodes and polarity protection diodes.

Features

- Compact Package with J-Bend Leads Ideal for Automated Handling
- Stable, High Temperature, Glass Passivated Junction
- AEC-Q101 Qualified and PPAP Capable
- NRVS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free*

Mechanical Characteristics:

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 95 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Maximum Temperature of 260°C / 10 Seconds for Soldering
- Polarity: Notch and/or Band in Plastic Body Indicates Cathode Lead
- ESD Ratings:
 - ♦ Machine Model = C
 - ♦ Human Body Model = 3A



ON Semiconductor®

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STANDARD RECOVERY RECTIFIER 1.5 AMPERES, 400 VOLTS



SMB CASE 403A PLASTIC

MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week RGG = Device Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MRS1504T3G	SMB (Pb-Free)	2,500 / Tape & Reel
NRVS1504T3G	SMB (Pb-Free)	2,500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MRS1504T3G, NRVS1504T3G

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	400	٧
Average Rectified Forward Current (At Rated V _R , T _I = 118°C)	lo	1.5	Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _I = 118°C)	I _{FRM}	3.0	А
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I _{FSM}	50	Α
Storage/Operating Case Temperature Range	T _{stg} , T _C	-55 to 150	°C
Operating Temperature Range	T _J	-55 to 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 1)	R _{tjl}	18	°C/W
Thermal Resistance, Junction-to-Ambient (on 1" sq. Cu. PCB pattern)	R _{tja}	79	°C/W

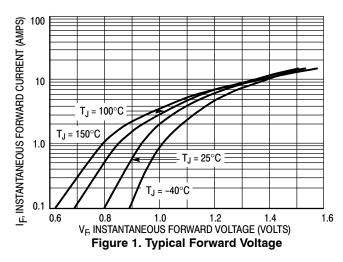
^{1.} Minimum pad size.

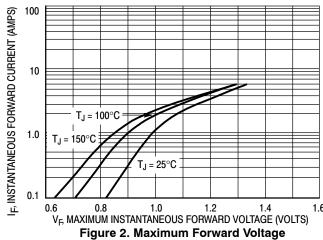
ELECTRICAL CHARACTERISTICS

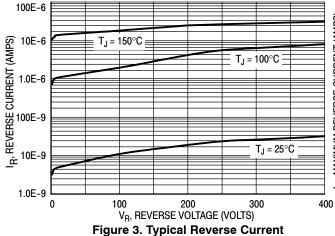
Rating	Symbol	T _J = 25°C	T _J = 100°C	Unit
Maximum Instantaneous Forward Voltage (Note 2), see Figure 2 ($I_F = 1.5 \text{ A}$) ($I_F = 2.25 \text{ A}$)	V _F	1.04 1.10	0.96 1.02	٧
Maximum Instantaneous Reverse Current, see Figure 4 (V _R = 400 V) (V _R = 200 V)	I _R	1.0 0.5	340 180	μΑ

^{2.} Pulse Test: Pulse Width ≤ 250 μs, Duty Cycle ≤ 2.0%

MRS1504T3G, NRVS1504T3G







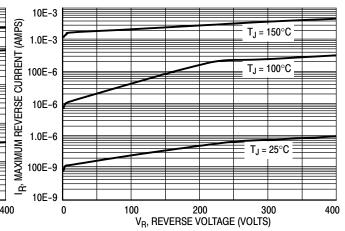
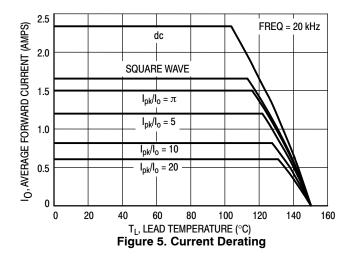


Figure 4. Maximum Reverse Current



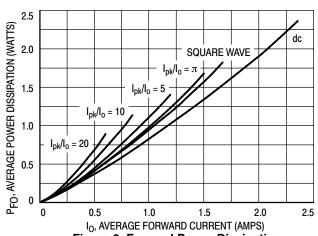


Figure 6. Forward Power Dissipation

MRS1504T3G, NRVS1504T3G

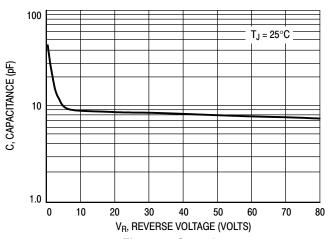


Figure 7. Capacitance

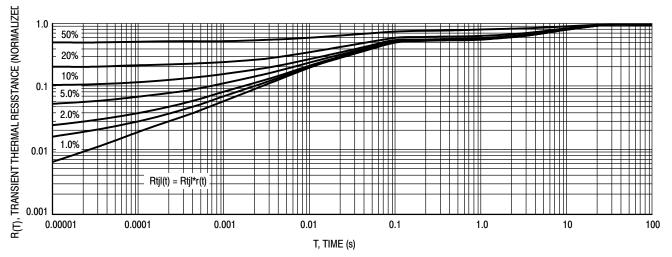


Figure 8. Thermal Response, Junction-to-Lead

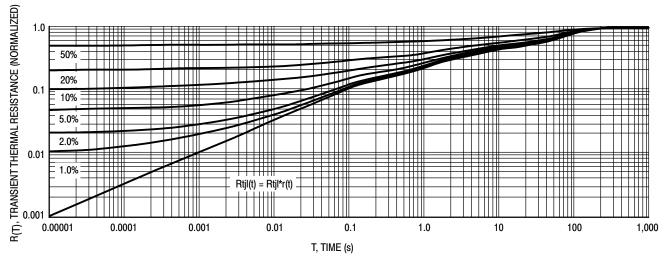


Figure 9. Thermal Response, Junction-to-Ambient



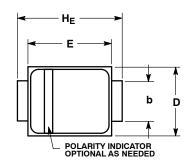


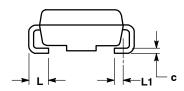
SMB CASE 403A-03 **ISSUE J**

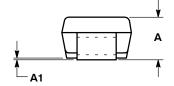
DATE 19 JUL 2012

SCALE 1:1 **Polarity Band**

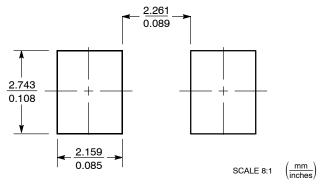
Non-Polarity Band







SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCL.
- 3. DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L1.

	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	MOM	MAX
Α	1.95	2.30	2.47	0.077	0.091	0.097
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.96	2.03	2.20	0.077	0.080	0.087
С	0.15	0.23	0.31	0.006	0.009	0.012
D	3.30	3.56	3.95	0.130	0.140	0.156
E	4.06	4.32	4.60	0.160	0.170	0.181
HE	5.21	5.44	5.60	0.205	0.214	0.220
L	0.76	1.02	1.60	0.030	0.040	0.063
L1		0.51 REF			0.020 REF	

GENERIC MARKING DIAGRAM*





Polarity Band

Non-Polarity Band

XXXXX = Specific Device Code = Assembly Location Α

= Year WW = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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